

# Dual Bias Resistor Transistor

The LMBT3906DW1T1 device is a spin-off of our popular SOT-23/SOT-323 three-lead device. It is designed for general purpose amplifier applications and is housed in the SOT-363 six-lead surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

- hFE, 100–300
- Low  $V_{CE(sat)}$ ,  $\leq 0.4\text{ V}$
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Available in 8 mm, 7-inch/3,000 Unit Tape and Reel
- Device Marking: LMBT3906DW1T1G = A2

## Features

- We declare that the material of product compliance with RoHS requirements.
- S - Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

## MAXIMUM RATINGS

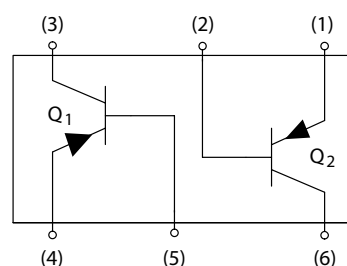
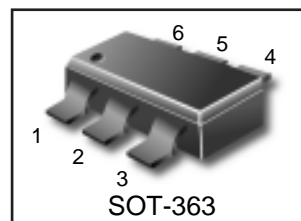
Rating	Symbol	Value	Unit
Collector–Emitter Voltage	$V_{CEO}$	–40	Vdc
Collector–Base Voltage	$V_{CBO}$	–40	Vdc
Emitter–Base Voltage	$V_{EBO}$	–5.0	Vdc
Collector Current – Continuous	$I_C$	–200	mAdc

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Package Dissipation <sup>(1)</sup> $T_A = 25^\circ\text{C}$	$P_D$	150	mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	833	$^\circ\text{C/W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	–55 to +150	$^\circ\text{C}$

1. Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended footprint.

**LMBT3906DW1T1G**  
**S-LMBT3906DW1T1G**



## ORDERING INFORMATION

Device	Marking	Shipping
LMBT3906DW1T1G	A2	3000 Units/Reel
S-LMBT3906DW1T1G	A2	10000 Units/Reel

**LMBT3906DW1T1G;S-LMBT3906DW1T1G**
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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**OFF CHARACTERISTICS**

Collector–Emitter Breakdown Voltage <sup>(2)</sup> ( $I_C = -1.0\text{ mAdc}$ , $I_E = 0$ )	$V_{(BR)CEO}$	-40	-	Vdc
Collector–Base Breakdown Voltage ( $I_C = -10\ \mu\text{Adc}$ , $I_E = 0$ )	$V_{(BR)CBO}$	-40	-	Vdc
Emitter–Base Breakdown Voltage ( $I_E = -10\ \mu\text{Adc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	-5.0	-	Vdc
Base Cutoff Current ( $V_{CE} = -30\text{ Vdc}$ , $V_{EB} = -3.0\text{ Vdc}$ )	$I_{BL}$	-	-50	nAdc
Collector Cutoff Current ( $V_{CE} = -30\text{ Vdc}$ , $V_{EB} = -3.0\text{ Vdc}$ )	$I_{CEX}$	-	-50	nAdc

**ON CHARACTERISTICS (2)**

DC Current Gain ( $I_C = -0.1\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ ) ( $I_C = -1.0\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ ) ( $I_C = -10\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ ) ( $I_C = -50\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ ) ( $I_C = -100\text{ mAdc}$ , $V_{CE} = -1.0\text{ Vdc}$ )	$h_{FE}$	60 80 100 60 30	- - 300 - -	-
Collector–Emitter Saturation Voltage ( $I_C = -10\text{ mAdc}$ , $I_B = -1.0\text{ mAdc}$ ) ( $I_C = -50\text{ mAdc}$ , $I_B = -5.0\text{ mAdc}$ )	$V_{CE(sat)}$	- -	-0.25 -0.4	Vdc
Base–Emitter Saturation Voltage ( $I_C = -10\text{ mAdc}$ , $I_B = -1.0\text{ mAdc}$ ) ( $I_C = -50\text{ mAdc}$ , $I_B = -5.0\text{ mAdc}$ )	$V_{BE(sat)}$	-0.65 -	-0.85 -0.95	Vdc

**SMALL–SIGNAL CHARACTERISTICS**

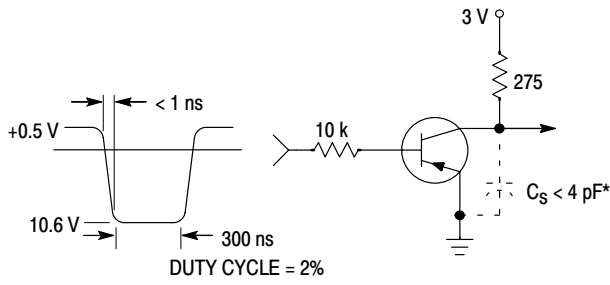
Current–Gain – Bandwidth Product	$f_T$	250	-	MHz
Output Capacitance	$C_{obo}$	-	4.5	pF
Input Capacitance	$C_{ibo}$	-	10	pF
Input Impedance ( $V_{CE} = -10\text{ Vdc}$ , $I_C = -1.0\text{ mAdc}$ , $f = 1.0\text{ kHz}$ )	$h_{ie}$	2.0	12	$k\ \Omega$
Voltage Feedback Ratio ( $V_{CE} = -10\text{ Vdc}$ , $I_C = -1.0\text{ mAdc}$ , $f = 1.0\text{ kHz}$ )	$h_{re}$	0.1	10	$\times 10^{-4}$
Small–Signal Current Gain ( $V_{CE} = -10\text{ Vdc}$ , $I_C = -1.0\text{ mAdc}$ , $f = 1.0\text{ kHz}$ )	$h_{fe}$	100	400	-
Output Admittance ( $V_{CE} = -10\text{ Vdc}$ , $I_C = -1.0\text{ mAdc}$ , $f = 1.0\text{ kHz}$ )	$h_{oe}$	3.0	60	$\mu\text{mhos}$
Noise Figure ( $V_{CE} = -5.0\text{ Vdc}$ , $I_C = -100\ \mu\text{Adc}$ , $R_S = 1.0\text{ k}\ \Omega$ , $f = 1.0\text{ kHz}$ )	NF	-	4.0	dB

**SWITCHING CHARACTERISTICS**

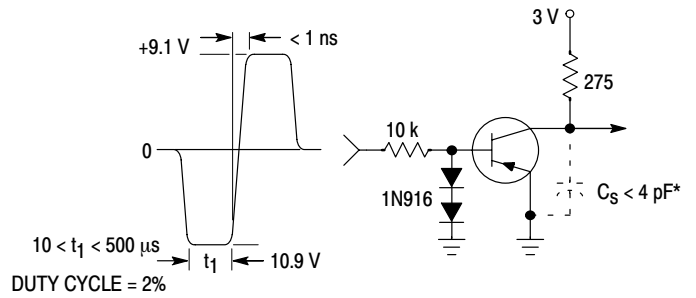
Delay Time	( $V_{CC} = -3.0\text{ Vdc}$ , $V_{BE} = 0.5\text{ Vdc}$ )	$t_d$	-	35	ns
Rise Time	( $I_C = -10\text{ mAdc}$ , $I_{B1} = -1.0\text{ mAdc}$ )	$t_r$	-	35	
Storage Time	( $V_{CC} = -3.0\text{ Vdc}$ , $I_C = -10\text{ mAdc}$ )	$t_s$	-	225	ns
Fall Time	( $I_{B1} = I_{B2} = -1.0\text{ mAdc}$ )	$t_f$	-	75	

 2. Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ ; Duty Cycle  $\leq 2.0\%$ .

**LMBT3906DW1T1G ;S-LMBT3906DW1T1G**



**Figure 1. Delay and Rise Time Equivalent Test Circuit**

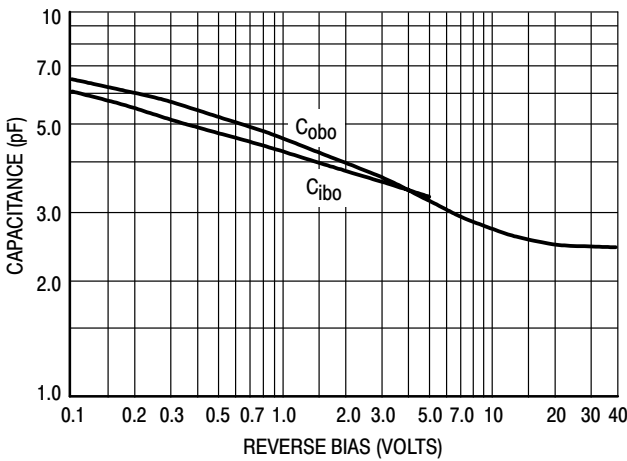


**Figure 2. Storage and Fall Time Equivalent Test Circuit**

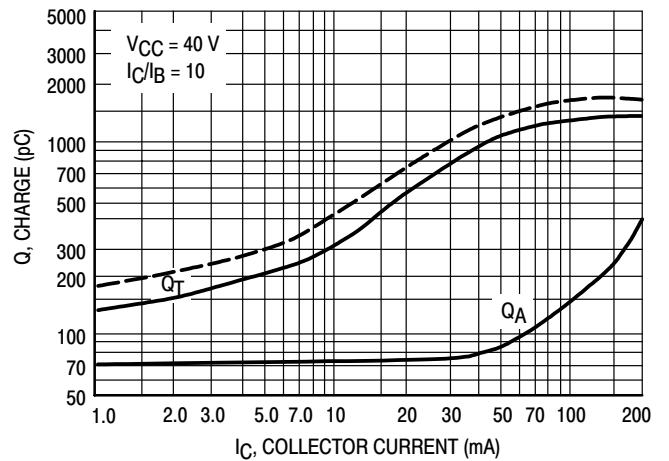
\* Total shunt capacitance of test jig and connectors

**TYPICAL TRANSIENT CHARACTERISTICS**

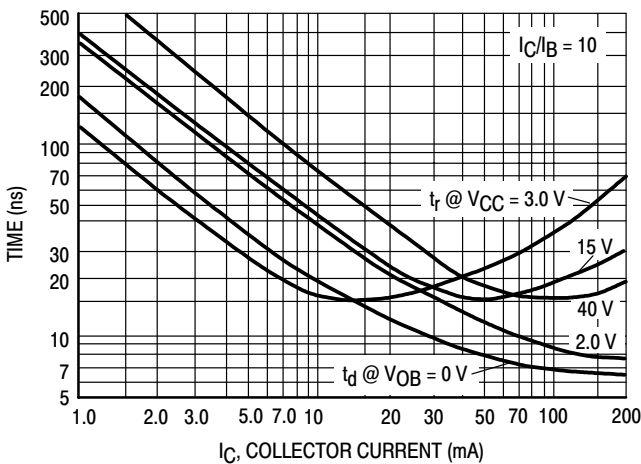
—  $T_J = 25^\circ\text{C}$   
 - - -  $T_J = 125^\circ\text{C}$



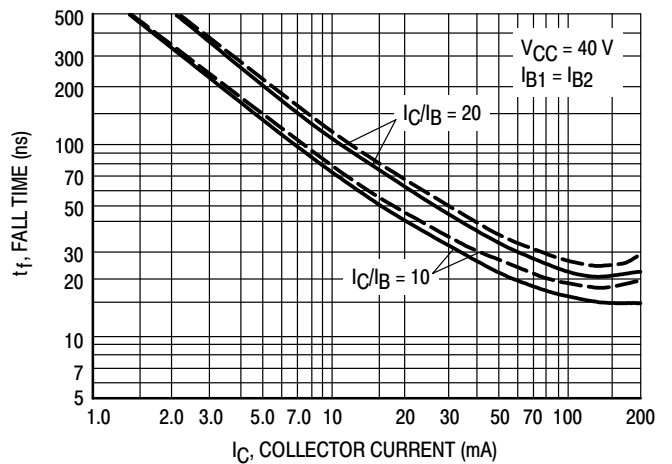
**Figure 3. Capacitance**



**Figure 4. Charge Data**



**Figure 5. Turn-On Time**



**Figure 6. Fall Time**

LMBT3906DW1T1G;S-LMBT3906DW1T1G

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS  
NOISE FIGURE VARIATIONS

( $V_{CE} = -5.0$  Vdc,  $T_A = 25^\circ\text{C}$ , Bandwidth = 1.0 Hz)

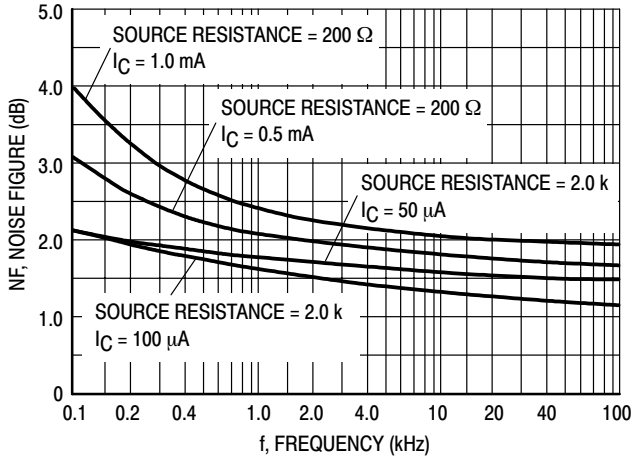


Figure 7.

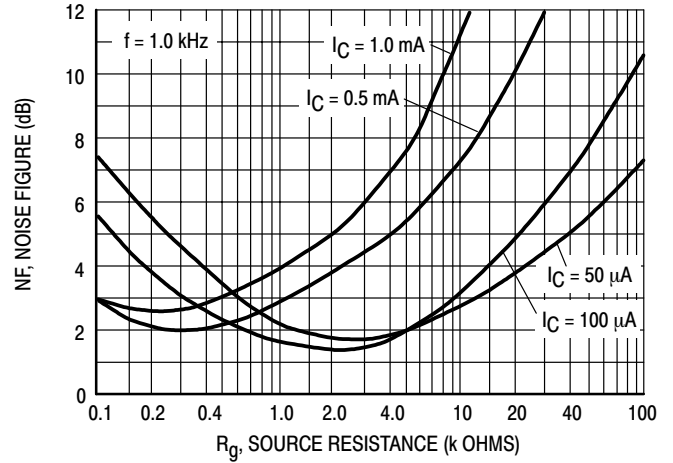


Figure 8.

h PARAMETERS

( $V_{CE} = -10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$ )

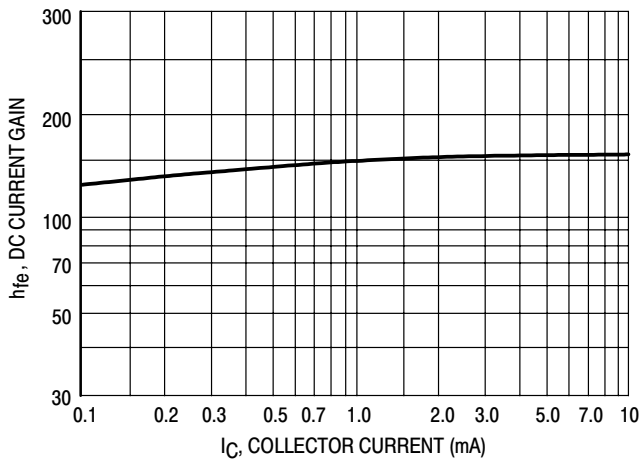


Figure 9. Current Gain

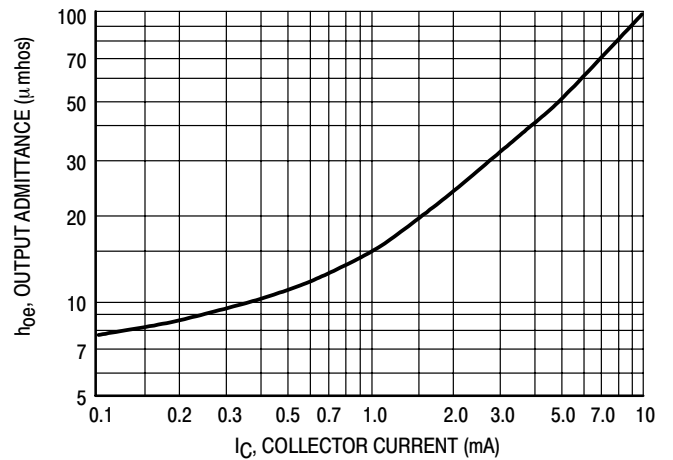


Figure 10. Output Admittance

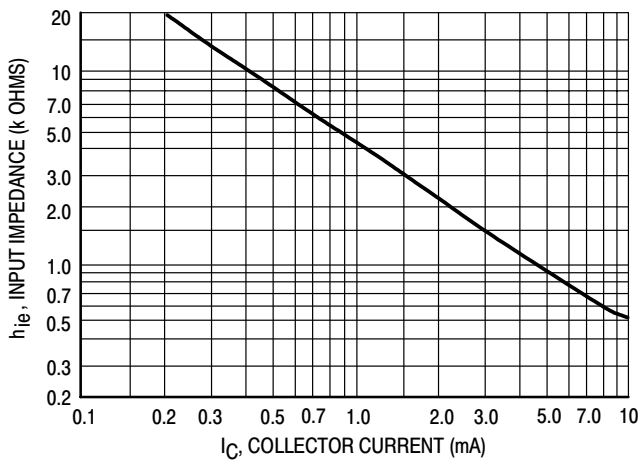


Figure 11. Input Impedance

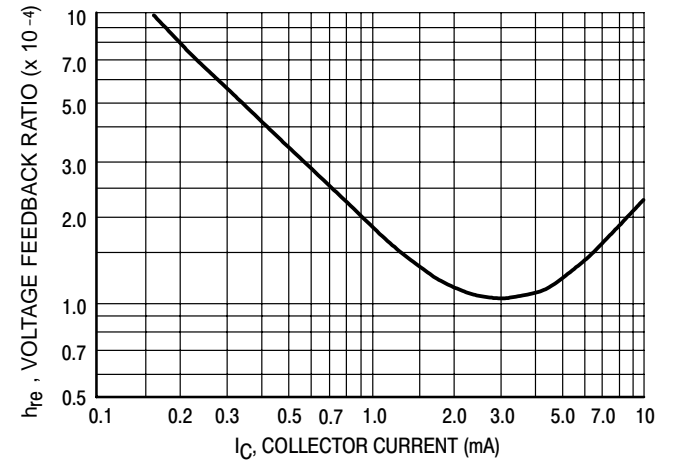


Figure 12. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

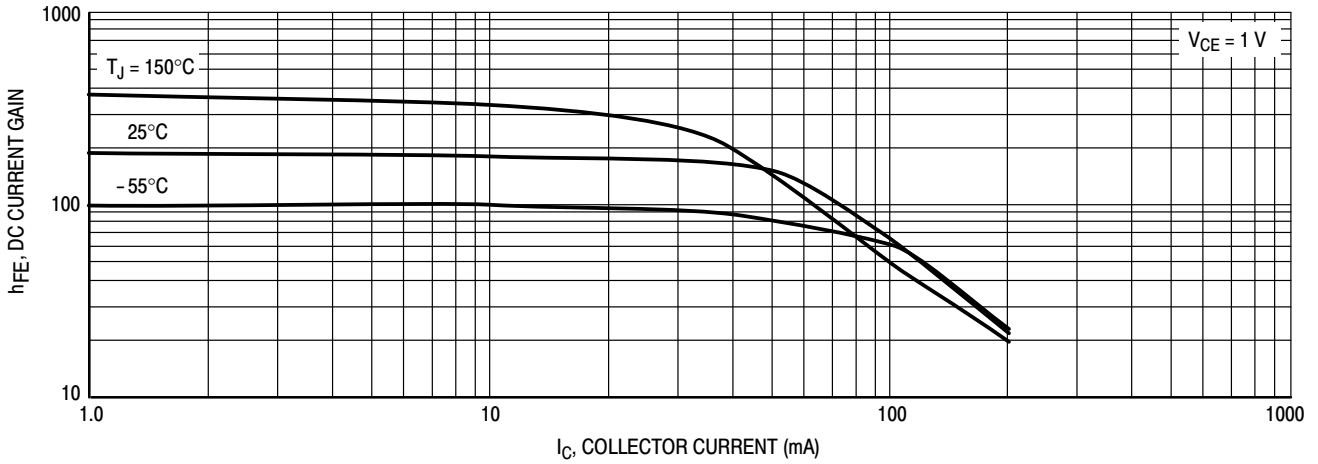


Figure 13. DC Current Gain

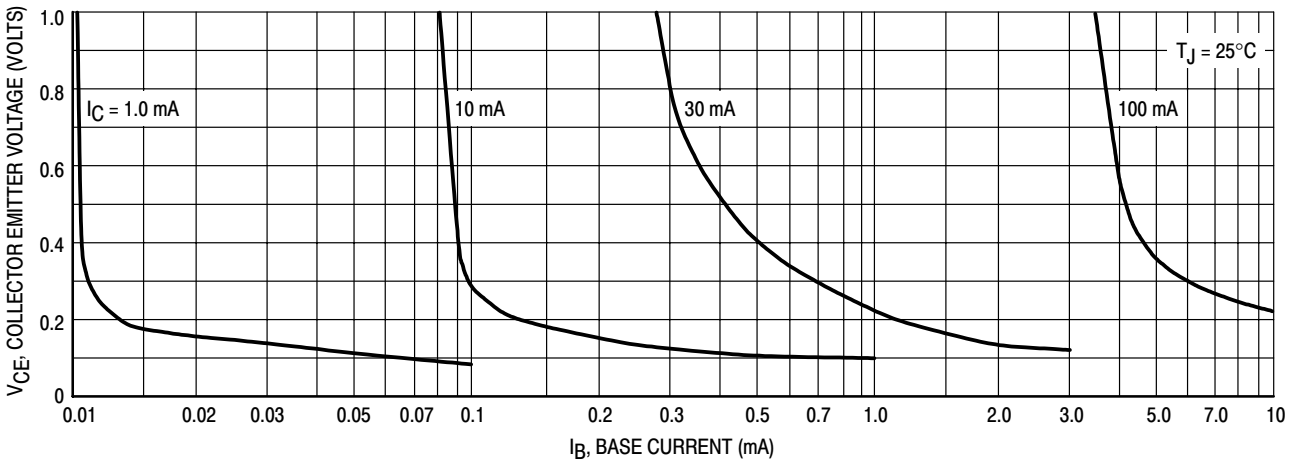


Figure 14. Collector Saturation Region

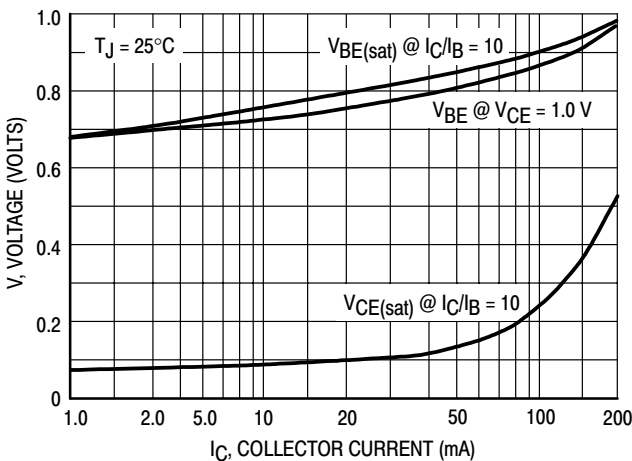


Figure 15. "ON" Voltages

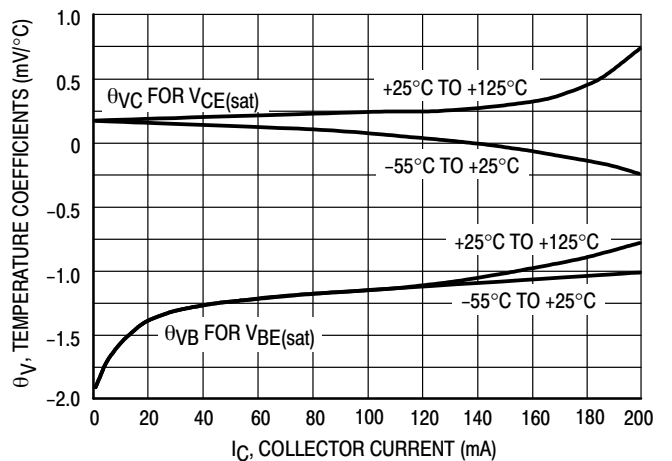
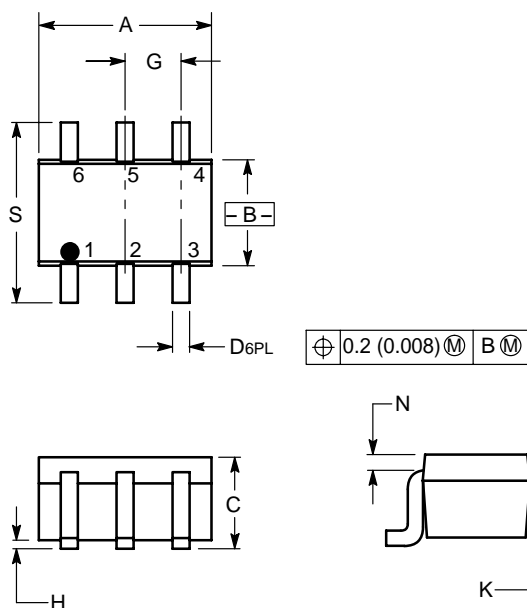


Figure 16. Temperature Coefficients

SC-88/SOT-363



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

- PIN 1. EMITTER 2
- 2. BASE 2
- 3. COLLECTOR 1
- 4. EMITTER 1
- 5. BASE 1
- 6. COLLECTOR 2

